

10A10

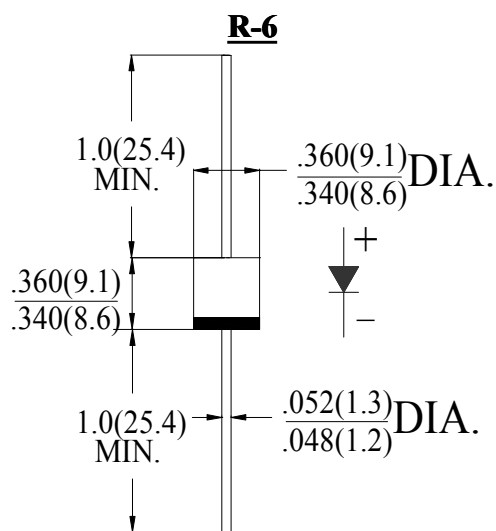
10.0AMPS SILICON RECTIFIERS

FEATURE

- . High current capability
 - . Low forward voltage drop
 - . Low power loss, high efficiency
 - . High surge capability
 - . High temperature soldering guaranteed
- 260°C /1 0sec/0.375" lead length at 5 lbs tension

MECHANICAL DATA

- . Terminal: Plated axial leads solderable per MIL-STD 202E, method 208C
- . Case: Molded with UL-94 Class V-0 recognized Flame Retardant Epoxy
- . Polarity: color band denotes cathode
- . Mounting position: any



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	SYM BOL	10A10	units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	1000	V
Maximum RMS Voltage	V_{RMS}	700	V
Maximum DC blocking Voltage	V_{DC}	1000	V
Maximum Average Forward Rectified Current. 375" (9.5mm) lead length @ $T_A=50^{\circ}C$	$I_{F(AV)}$	10	A
Peak Forward Surge Current 8.3ms single half sine- wave superimposed on rated load (JEDEC method)	I_{FSM}	400	A
Maximum Forward Voltage at 10.0A DC	V_F	1.0	V
Maximum DC Reverse Current $T_A=25^{\circ}C$ at rated DC blocking voltage $T_A=100^{\circ}C$	I_R	10 200	μA
Typical Junction Capacitance (Note1)	C_J	100	pF
Typical Thermal Resistance (Note2)	$R_{(JA)}$	40	$^{\circ}C/W$
Storage Temperature	T_{STG}	-55 to +150	$^{\circ}C$
Operation Junction Temperature	T_J	-55 to +150	$^{\circ}C$

Note:

1. Measured at 1.0 MHz and applied reverse voltage of 4.0Vdc
2. Thermal Resistance from Junction to Ambient at 0.375" (9.5mm) lead length

RATING AND CHARACTERISTIC CURVES (10A10)

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

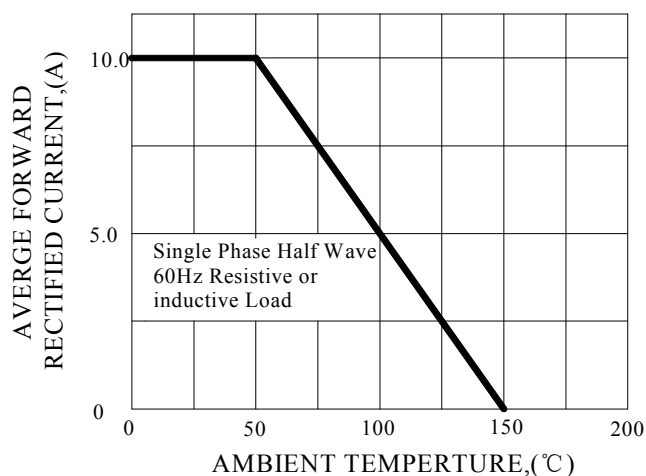


FIG.2-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

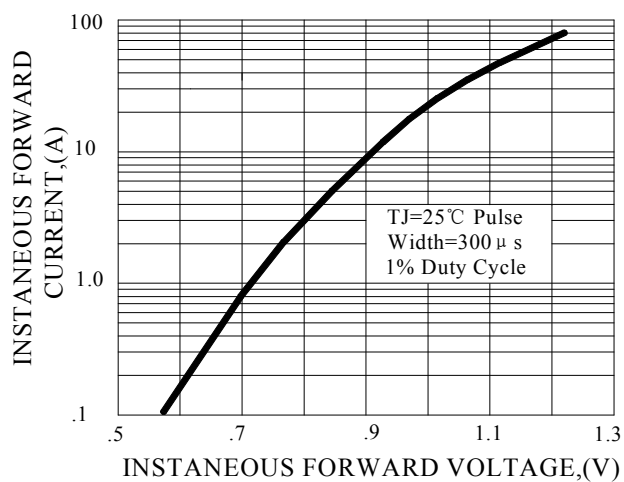


FIG.3-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

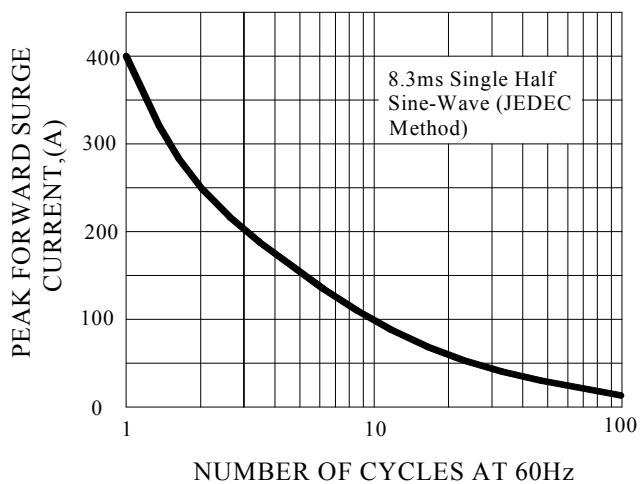


FIG.4-TYPICAL REVERSE CHARACTERISTICS

